NSN 5961-01-439-2392

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Demilitarization:

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-439-2392 **Inclosure Material:** Ceramic **Overall Length:** 0.180 inches **Overall Height:** 0.065 inches **Overall Width:** 0.180 inches **End Application:** An/prc-11 (v) e/i fscm 04655 **Internal Configuration:** Field effect **Mounting Method:** Compression **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 drain to gate voltage and 30.00 drain to source voltage and 30.0 drain to substrate voltage **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 1.2 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Plated leads gold **Test Data Document:** 04655-13-2728240 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 case Shelf Life: N/a **Unit Of Measure:**